Localized heating and thermal characterization of high electrical resistivity silicon-on-insulator sensors using nematic liquid crystals

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We present a method for localized heating of media at the surface of silicon-on-insulator field-effect sensors via application of an ac voltage across the channel and the substrate and compare this technique with standard Joule heating via the application of dc voltage across the source and drain. Using liquid crystals as the medium to enable direct temperature characterization, our results show that under comparable bias conditions, heating of the medium using an alternating field results in a greater increase in temperature with a higher spatial resolution. These features are very attractive as devices are scaled to the nanoscale dimensions. © 2008 American Institute of Physics.

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Localized heating schemes can allow for the spatial and temporal downscaling of temperature dependent reactions for miniaturized lab-on-a-chip. Temperature control at the micro and nanoscale has the potential to enable many applications including control of probe-target interaction,1,2 selective functionalization of the sensor surfaces,3 realizing active surfaces,4 and highly localized polymerase chain reaction (PCR).5,6 Control of this temperature profile over silicon based field-effect electrical biosensors7 will add another dimension to the functionality of these devices. For these silicon-based field-effect biosensors, a high resistance is appealing for high sensitivity label-free detection of biomolecules.8 Electrical Joule heating of high resistance devices is challenging since it requires the application of high electric fields to enable enough current flow to heat the device, which can be highly problematic in fluids. Also, heat transfer to both the substrate and the medium limits the increase in temperature and increases the thermal mass of the system. In this work, we fabricated a silicon-on-insulator field effect sensor9 as was previously reported[Fig. 1(a) (width of 2 μm and length of 20 μm)] and characterized the surface temperature while heating the surrounding media using two different methods. The device active area is 20 nm in thickness (p type ~10^{15} cm^{-2}) with a buried oxide thickness of 400 nm and a p type substrate (10^{15} cm^{-2}). First we investigate the Joule heating of the fluid surrounding the device by passing a direct current [Fig. 1(b)]. Next, we directly heat the surrounding fluid by applying an ac voltage between the device and the substrate [Fig. 1(c)]. Such a direct heating scheme for the localization of the heat profile has been demonstrated using only metal leads and at a larger scale.10 We used liquid crystal (LC) films as the surrounding medium, which have been used for hot spot detection of integrated circuits,11 to directly characterize the temperature by observing the film through a polarizer orthogonal to the incident polarized light. Nematic LCs available with various clearing temperatures (transition in optical properties) allow characterization of different surface temperatures. Nematic LC films can allow temperature characterization with high spatial resolution and greater ease compared with other established techniques. For example, infrared thermography cannot be used due to the limits in the resolution and the fluidic environment.12 Using thermochromic LC beads allows for temperature mapping in fluid13 but does not provide the spatial resolution needed due to the bead size. Fluorescent dyes in fluid, which have shown to be temperature sensitive and exhibit reversible characteristics,12,14 could be used; however, due to the highly localized nature of the ac voltage heating, the background fluorescence inhibits accurate characterization of the surface temperature.15

In order to characterize the temperature increase achievable by Joule heating of the active area via direct current through the devices [shown in Fig. 1(b)], LCs (Accelerated Analysis, Inc.) were applied by brushing the film onto the devices and still photographs were acquired at different bias conditions [Figs. 2(a)–2(d)]. The power required to reach a specific temperature was quantified by analyzing the average intensity of the devices. The intensity over the active area of the device was correlated with the input power, which revealed the transition voltage. A representative plot is shown in Fig. 2(e). A sigmoidal curve fit was performed, and the inflection point is taken as the voltage that results in a specific temperature above the device. To maximize the conductance through the device, the back gate was biased to 30 V to accumulate the device. The ambient temperature through a heated chuck was modulated to quantify different temperature increases using the same film [Fig. 2(f)]. The average temperature increase in the device was characterized with different transition point LCs and a maximum temperature increase of 14 °C was obtained for a source/drain potential difference of 40 V. To investigate ac voltage mediated heating, LCs were once again applied to the same devices. Voltages were applied [Fig. 1(c)] using a function generator connected to a rf power amplifier at constant frequency of 100 kHz. Still pho-

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Figures 3a–3d were acquired and quantified at different bias points [Fig. 3(e)]. LCs with varying clearing temperatures (35, 60.5, and 90 °C) were used to quantify the maximum obtainable temperature. Local heating up to 90 °C at an ambient temperature of 21 °C was observed with the application of 17.5 Vrms.

For ac heating, we observe that temperature is confined strictly to the edges of the device with no further propagation. However, the temperature profile originally confined to the 2 μm wide active area diffuses at about 0.8 μm to each side for dc heating from 7 to 14 °C, which is exacerbated by larger increases in temperature. The highly confined temperature profile at the edges of the device for ac heating indicates that the heating is due to the fringing electric field between the active area and the substrate. Dielectric heating dominates over conductive heating due to the high frequencies being used. Using an ac heating technique minimizes the electric field in the medium compared with dc heating techniques, which is crucial for fluidic applications to prevent unwanted reactions or breakdown of insulators. Although the technique still requires finite electric field in the medium, no potential difference exists between the source and drain electrodes for ac heating, whereas a 40 V potential was necessary for dc heating. Furthermore, the peak potential difference needed between the substrate and the source/drain electrode was 25 V for ac heating and about 70 V for dc heating.
For a constant temperature increase, when input power is plotted versus frequency, a curve independent of frequency is expected since input power is correlated with temperature. Plotting \( \frac{1}{2} |E|^2 \omega \varepsilon_{\infty}^{\prime} / \varepsilon_0 \) versus the frequency for different temperature differences achieved by heating should result in frequency independent curves for different increases in temperature. Figure 3(f) shows the experimental results obtained, assuming a loss tangent that is proportional to \( \omega^{2.8} \) for the calculation of theoretical power resulting in a nearly frequency independent behavior. The results indicate that a surface temperature increase is responsible for changes in optical properties of the LCs, instead of side effects of the applied ac voltage.

In conclusion, we use nematic LC films to characterize the surface temperature and quantitatively compare two different heating schemes. We find that it is better to use an ac electric field for the direct heating of the fluid for high resistivity devices as compared with dc voltage for achieving both a larger temperature increase and a higher spatial resolution, which are key considerations as devices continue to be aggressively scaled down. This also allows us to keep the electric field at a minimum to prevent dielectric breakdown and unwanted chemical reactions for applications in fluid.

The technique can potentially be used for the direct heating of a wide range of fluids, and the optimum operating frequency will depend on the characteristic of the fluid. Further experimental and simulation work is underway for characterizing the heating of fluids using the ac technique. Direct heating of fluids in a localized fashion, as demonstrated in this work, has many technological applications in lab-on-a-chip systems, such as achieving densely integrated active surfaces or localized PCR modules with built-in sensors.